

Circuit Analysis for Analog Designers
Prof. Shanthi Pavan
Department of Electrical Engineering
Indian Institute of Technology, Madras

Lecture - 41
Noise Factor Examples

(Refer Slide Time: 00:16)

→ v_n is of no consequence

Noise Factor (Noise Figure)

Case 1: Null all internal noise sources
 Output noise → v_n

Case 2: All noise sources are activated
 Output noise → v_{n_2}

$v_{n_2}^2 > v_n^2$ $\frac{v_{n_2}^2}{v_n^2} \geq 1$ $\left\{ \begin{array}{l} \text{Quantifies the} \\ \text{SNR degradation caused by} \\ \text{the amplifier} \end{array} \right.$

$10 \log_{10}(NF) = \text{Noise Figure (in dB)}$

So, alright so, let us do you know some quick examples to help you figure out what the noise factor is.

(Refer Slide Time: 00:33)

Output noise → v_{n_2}

$v_{n_2}^2 > v_n^2$ $\frac{v_{n_2}^2}{v_n^2} \geq 1$ $\left\{ \begin{array}{l} \text{Quantifies the} \\ \text{SNR degradation caused by} \\ \text{the amplifier} \end{array} \right.$

$10 \log_{10}(NF) = \text{Noise Figure (in dB)}$

$NF = \frac{4kT(R_p || R_s)}{4kT R_s \left(\frac{R_p}{R_s + R_p}\right)^2} = \frac{R_p R_s}{(R_p + R_s) R_s \frac{R_p^2}{(R_s + R_p)^2}}$

So, let us say these are source, this is R_s and this is within quotes are black box and I am going to say well, my black box simply is got a resistor R_p alright. Now, what comment can we make about the noise factor, what do we do? We need to find the output noise correct and we need to find the output noise assuming the box itself is noiseless. So, what is the output noise spectral density? What is the output voltage noise spectral density?

It is $4kT$ times, Pardon. Why R_p by R_p plus R_s is a whole square? It is simply. What is the output noise voltage spectral density? $4kT R_p$ parallel R_s . Any confusion about this ok?

$$NF = \frac{4kT (R_p || R_s)}{4kT R_s \frac{R_p}{R_s + R_p}}$$

Now, you have to divide this by the output noise spectral density that would have resulted provided which was noiseless? R_p was noiseless, now what would be the output noise spectral density? It is $4kT$ times R_s that is the noise spectral density of this resistor right and how what is the transfer function from this noise source to the output?

R_p by; R_p by R_s plus R_p so, what should I do?

$$NF = \frac{4kT (R_p || R_s)}{4kT R_s \frac{R_p}{R_s + R_p}}$$

This the noise spectral density is going through within quotes again so, we have to multiply by again square correct

$$NF = \frac{4kT (R_p || R_s)}{4kT R_s \left(\frac{R_p}{R_s + R_p} \right)^2}$$

And therefore, this is nothing but $4kT$ goes away so, this is $R_p R_s$ divided by R_p plus R_s times R_s times R_p square by R_s plus R_p d whole square alright

$$NF = \frac{4kT (R_p || R_s)}{4kT R_s \left(\frac{R_p}{R_s + R_p} \right)^2} = \frac{R_p R_s}{(R_p + R_s) \frac{R_s R_p^2}{(R_s + R_p)^2}}$$

and therefore, this goes away, this goes away, this goes away, this goes away, this goes away this goes away.

(Refer Slide Time: 03:42)

NPTEL

v_s R_s R_p

$$NF = \frac{4kT(R_p || R_c)}{4kT R_c \left(\frac{R_p}{R_s + R_p}\right)^2} = \frac{1}{\frac{R_p}{R_s + R_p}}$$

$$NF = 1 + \frac{R_s}{R_p}$$

Assume $R_p = R_s$

So, this is nothing but, the noise factor is nothing but 1 plus R s over R right,

$$NF = 1 + \frac{R_s}{R_p}$$

Sanity check well, R p is infinity, what should we expect? Well, you are not doing anything so, presumably you are not losing SNR so, I mean sure enough you get noise factor of 1 or 0 right and I mean well, within I mean we said this is our amplifier so to speak, but you know what you are actually doing is attenuating correct ok. So, if you simply attenuate with the resistive attenuator as you can see this is telling you that you are always going to be. I mean you are going to be degrading the SNR right ok and you know why does that make sense?

Student: (Refer Time: 05:00) added additional (Refer Time: 05:08).

Ok well, yeah that is I mean I guess that is right. So, what comment can you make about the absolute noise spectral density at the output has that let us assume; let us assume for argument's sake that R s is equal to R p is made equal to R s right. So, what comment can we make about the noise spectral density at the output when compared to R p is equal to infinity?

Student: (Refer Time: 05:40) R p (Refer Time: 05:43).

It is what comment can we make about the output noise spectral density if R_p is equal to R_s ?

If you know $4kT$ times R you know R_s by 2. So, the noise spectral density at the output is actually gone down, that does not mean that the signal is becoming any I mean the signal to noise ratio is improving why?

Oh well, the signal is also attenuated by the same factor which basically means the signal power has gone down by 1 by 4.

Right ok noise has gone down by half, but the signal power has gone down by a factor of 1 by a factor of 4 so, the SNR has gone down by a factor of. The noise power has gone down by factor of 2, signal power has gone down by a factor of 4, what comment can we make about the SNR?

The signal they say as the SNR has actually gone down by a factor of 2 even though the noise flow has actually reduced by a factor of 2 right and that is also, that is what the equation is telling us if R_s is equal R_p then the noise factor is 2 which means that the output SNR is lower than the input SNR by a factor of 2. The noise factor does not say anything about the absolute noise flow, it is only quantifying how badly you done with respect to 2 SNR right. Let us do another example.

(Refer Slide Time: 07:24)

The slide contains the following content:

- NPTEL logo** in the top left corner.
- Handwritten text: "Assume $R_p = R_s$ ".
- A circuit diagram showing a signal source v_{gs} connected to a load R_L . A noise source $4kT\eta g_m$ is added in parallel with the load. The output voltage is v_o .
- Another circuit diagram showing a noise source v_n connected to a load R_L .
- Equation for noise factor: $NF = 4kT R_s (g_m R_s)^2 + 4kT \eta g_m$.
- Equation for output voltage: $v_o = \frac{v_n}{R_L}$.
- Equation for output power: $S_o(f) = \left(\frac{1}{R_L}\right)^2 S_{v_n}(f)$.
- Equation for noise power: $= \frac{1}{R_L^2} \cdot 4kT \cdot R_L$.
- Equation for noise spectral density: $= 4kT/R_L$.
- Handwritten text: $4kT\eta g_m$ at the bottom.

Now, let us take a transistor and at low frequency, what comment can we make about what is the small signal equivalent of the transistor? It is nothing but this is the incremental v_{gs} so, this is g_m times v_{gs} , this is r_o and as I mentioned the transistors accompanied by a noise source whose spectral density is for a long channel MOS transistor can be shown to be $8kT$ over 3 times g_m , but then you know long channel MOS transistors you know only exist in the textbooks.

So, what a better formula is to use $4kT \eta$ times g_m right.

$$4kT\eta g_m$$

Well, that η is some number that fits measurements right η or γ or whatever they are they have some that is the usual non-ideality factor, ideally η should be two-thirds, in reality it is more like three-half's ok so, whatever right I mean this the designer has no control over what you get right, it is what you get.

And so, another thing I would like to point out is that even though you have a r_o which models the finite or non-zero λ of the device, it is not a physical resistance right and therefore, there is no noise as that current source is not the noise associated with it is not noise associated with that r_o ok and so, this is a simple model for noise in fact, it turns out that in reality, there is also another noise source in the gate, but that only becomes shows up at really high frequency, but for most calculations at least at low frequencies, this is good enough.

Now, let us do a simple common source amplifier whose incremental picture is shown here, and this is v_i , this is R_s and that is R_L . So, what comment can we make, how do we what is the noise factor, what do we do? First thing is to find the total output noise. So, what will be the total output noise, noise spectral density? Well, what is the gain from R_s to the voltage source and series with R_s to the output?

Yeah, well, let us assume again you know let us make life simple and assume that r_o is equal the infinity ok. So, what is the gain from the noise source to the output?

Minus $g_m R_L$ right. So, what will be the output noise spectral density due to R_s ? It is $4kT R_s$ times $g_m R_L$ minus $g_m R_L$ the whole square, which is the same as plus $g_m R_L$ the whole square right plus what else? Is that all?

$$NF = 4kTR_S(g_m R_L)^2 +$$

How many noise sources are there?

Student: (Refer Time: 11:02) R L (Refer Time: 11:05).

I mean the main thing here is the transistor man, how many noise sources do we have? 3 noise sources. Now, you know I mean with you know even I mean of course, the three you know noise sources we can say we can all do this you know in our minds, but you can imagine what will happen if you have you know 50 transistors like this and you know there is tons of noise sources and there is one output and you need to now calculate you know.

And I made r life simple by assuming r o is infinity and there is no parasitic capacitances etcetera, in reality all that stuff is going to go come in and then, it is going to be a mess so, that is where the adjoint is the inter reciprocal network is so useful right, because you write down the MNA equations of this big network, you solve it once ok and you get all the transfer functions that you are looking.

So, back to our example so, there are three noise sources fortunately, it seems like we can use some simple trick to convert that into two so, this noise source is that of the transistor and it has a $4kT \eta g_m$, the noise source resistor is a voltage source, but we know how to convert from not an equivalent to a Thevenin equivalent so, v_n in series with R L is equivalent to i_n in parallel with R L.

And what is i_n ? v_n by R L

$$i_n = \frac{v_n}{R_L}$$

So, the noise spectral density of the current source is nothing but well, you are multiplying that current by 1 by R L times v_n so, you multiply this by a constant so, you have to I mean you multiply that by 1 by R L square times $S_{v_n}(f)$ which is nothing but 1 over R L square times $4kT R_L$ so, this is nothing but $4kT$ over R L that makes sense guys.

$$S_z(f) = \left(\frac{1}{R_L}\right)^2 S_{V_n}(f)$$

$$= \frac{1}{R_L^2} 4kT R_L$$

$$= \frac{4kT}{R_L}$$

So, we have two noise sources here, one which corresponds to the transistor, one that corresponds to we are going to call that $4kT G_L$, ($4kT G_L$) ok. So, what is the total noise the at the output therefore? This is the input source plus what is the total noise voltage at the output now?

Yes Danish.

(Refer Slide Time: 14:04)

The slide shows a circuit diagram of a common-emitter amplifier. The input is a voltage source v_{n_s} in series with a source resistance R_S . The amplifier consists of a transistor with a noise source v_{n_t} and a load resistance R_L . A blue box highlights the amplifier's internal noise sources. The output voltage is v_o . Handwritten equations show the total output noise voltage $v_o = v_{n_s} + v_{n_t} + v_{n_L}$ and the noise factor $NF = \frac{4kT R_S (g_m R_L)^2 + 4kT (\eta g_m + G_L) R_L^2}{4kT R_S (g_m R_L)^2}$. The final simplified equation is $NF = 1 + \frac{(\eta g_m + G_L) R_L^2}{R_S g_m^2 R_L^2}$.

Student: $4kT \eta g_m$ plus G_L that is the current flows into R_L so, what should I; what should I do here? Very good R_L square, this is the total noise at the output of the amplifier right

$$\underline{4kT R_S (g_m R_L)^2 + 4kT (\eta g_m + G_L) R_L^2}$$

And you have divided this by the noise that you would have got if the amplifier itself was noiseless right. So, in other words everything inside this blue box if it was noiseless, what is the noise you would have got? What would you have got?

That is easy to do; it is simply $4kTR_s$ times $g_m R_L$ whole square.

$$NF = \frac{4kTR_s(g_m R_L)^2 + 4kT(\eta g_m + G_L)R_L^2}{4kTR_s(g_m R_L)^2}$$

So, this is the noise factor and therefore, the noise factor is 1 plus eta g_m plus G_L into R_L square divided by R_s times g_m square R_L square ok

$$NF = 1 + \frac{(\eta g_m + G_L)R_L^2}{R_s g_m^2 R_L^2}$$

And so, this goes away, this goes away.

(Refer Slide Time: 15:47)

The image shows a hand-drawn circuit diagram of a common-emitter amplifier. The input is a voltage source v_{gs} in series with a resistor R_s . The transistor's base is connected to this input. The collector is connected to a load resistor R_L . There are two noise sources: a current source i_{n1} with spectral density $4kT\eta g_m$ in parallel with the base-emitter junction, and a current source i_{n2} with spectral density $4kTG_L$ in parallel with the load resistor R_L . The output voltage is v_o . The derivation shows the total noise at the output is $S_{v_o}(f) = \left(\frac{R_L}{R_s}\right)^2 S_{v_{gs}}(f)$. The noise factor is then calculated as $NF = \frac{4kTR_s(g_m R_L)^2 + 4kT(\eta g_m + G_L)R_L^2}{4kTR_s(g_m R_L)^2}$, which simplifies to $NF = 1 + \frac{(\eta g_m + G_L)}{R_s g_m^2}$. A box highlights the final equation: $NF = 1 + \frac{\eta}{g_m R_s} + \frac{1}{(g_m R_s)(g_m R_L)}$.

And you have 1 plus eta over $g_m R_s$ alright plus 1 over $g_m R_s$ times $g_m R_L$ alright.

Now, why does this make intuitive sense or is there a sanity check?

$$NF = 1 + \frac{\eta}{g_m R_s} + \frac{1}{(g_m R_s)(g_m R_L)}$$

Well, if R_L you know was noiseless, the noise factor would be 1 plus eta over $g_m R_s$ ok.

Now, the what comment can we make about the noise spectral density added by the resistor in relation to that added by the transistor? Actually, I missed the no, I think we are ok yeah.

So, what comment can we add?

Student: (Refer Time: 17:05).

Yeah, so, basically you know when you refer, I mean adding a noise current here ok is equivalent I mean what disturbance at this node would cause a disturbance of $4kT$ I mean in other words, what disturbance must I add here at the gate to cause a current I in the drain?

Whatever disturbance there is in the drain current that has to be divided down by g_m right in order to right and so, if you are looking at the output voltage, you know this current will cause a you know will have a gain of only R_L whereas, a voltage here will have an effect of g_m times R_L ok.

So, you can see that the noise added by the resistor is I mean R_L is lot less important than the noise added by the transistor. Because if you choose a large gain $g_m R_L$ is a large number basically saying that the noise added by the resistor, noise current added by the resistor load resistor is much smaller than the noise current added by the transistor itself.

(Refer Slide Time: 18:47)

The slide displays a circuit diagram of a common-source amplifier. A noise current source is connected to the gate. The gate resistor is labeled R_S and the load resistor is labeled R_L . The transconductance of the transistor is g_m . The noise factor equation is given as:

$$NF = 1 + \frac{\gamma g_m + G_L}{R_S g_m^2}$$
$$NF = 1 + \frac{\gamma}{g_m R_S} + \frac{1}{(g_m R_S)(g_m R_L)}$$

The next thing I am going to do another example, but I am not going to go through the algebra, I leave you to do the algebra, but I am going to what I would like to discuss is intuitively what we should expect so, the two-stage amplifier, this is g_{m1} , R_1 , g_{m2} , R_2 alright and so, which I mean based on your experience so far, which, what do you think

who I mean which of the noise sources do you think is the most contributes the most to the noise figure? g_m ? g_{m1} right why? Initially why does it make sense?

Student: (Refer Time: 19:51).

Well, yeah that is right I mean any the noise source, any noise added by the transistor, the noise current is now know converted into voltage that is further amplified so, a lot of the noise here will be due to g_{m1} and R_s .

And as you keep going further down the chain let us say you have a long cascade right, the noise figure is going to be if you have; if you have a cascade of amplifiers each one which is amplifying the signal right and of course, also amplifying noise from preceding stages, which of the stages will be the most; which of the stages would you expect is the most critical as far as the noise is concerned?

The first stage right ok. And which do you think you know as you keep travelling down the chain, the signal is getting bigger and bigger so, I you know which would you worry about uh you know distorting the signal a lot?

Well yeah, the last stages are the ones which you should be primarily worried about as far as distortion is concerned and the first stages are the ones that you would be worried about primarily about noise right and that is how it goes.

So, that is all I had to say regarding noise factor and noise figure and you should be in a I mean and the you know again I would like to remind you that so far, we have just discussed you know circuits where there is no memory so that the algebra becomes easier on the blackboard right.

In reality, all these transfer functions will have will there be frequency dependence if all these gains and stuff like that so, basically wherever you see a gain, you replace it with a transfer function and therefore, in general, noise factor is a function of; it is a function of frequency because gain is a function of frequency alright. So, that basically is all I had to say about the noise factor.